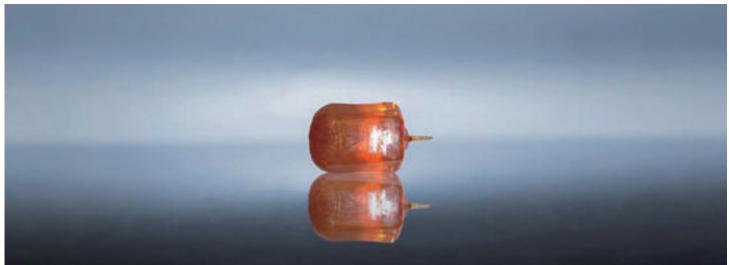


LGS



DESCRIPTION

LGS crystal, also known as lanthanum gallium silicate crystal with the chemical formula La₃Ga₅SiO₁₄, is a nonlinear optical crystal with excellent electro-optical properties.LGS crystal belongs to the triangular crystal system structure with a small thermal expansion coefficient, weak thermal expansion anisotropy of the crystal, two independent electro-optical coefficients, and the electro-optical coefficient is stable in a wide temperature range. The crystal has good mechanical properties, no deliquescence, good physical and chemical stability, high damage threshold, high electro-optical coefficient, excellent electro-optical properties, low thermal expansion coefficient, good high-temperature stability, etc. It has wide applications in electro-optical Q-switches, SAW devices, BAW devices, and high power high repetition rate all-solid-state lasers.

FEATURES

- High damage threshold
- Good Spinability
- Low Equivalent Series Resistance
- Stable physical and chemical properties
- High electromechanical coupling coefficient

APPLICATIONS

- Electro-optical Q-switch
- SAW equipment
- RAW equipment
- Sensors
- High Power High Repetition Rate All Solid State Lasers
- Can withstand high and low temperature variations

CRYSTAL SPECIFICATIONS

Direction	±15′
Wavefront distortion	<λ/8 @633nm
Extinction ratio	>500:1
Diameter Tolerance	+0.00mm/-0.05mm
Length Tolerance	±0.2mm
Chamfering	<0.1mm @45°
Flatness	<λ/10 @633nm
Parallelism	<3 arc min
Perpendicularity	<5 arc min
Surface quality	10/5
Permeability enhancement film	<0.3% @1064nm



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LGS CRYSTAL CHARACTERISTICS

Point group	32
Space group	p321
Electrical resistivity	4.0×1012Ω/cm ⁻¹
Thickness	0.13-0.5mm
Diameter	50mm
Length	90-100mm
Melting point	1470°C
Density	5.67g/cm ³
Mohs Hardness	5.5
Optical damage threshold	670MV/cm ²
Cell parameters	a=b=0.8162nm,c=0.5087nm
Dielectric constant —	ε ₁₁ =18.27
	ε ₃₃ =55.26
Electro-optical coefficient —	γ ₁₁ =2.3×10-12m/V
	γ ₃₃ =1.8×10-12m/V
Piezoelectric strain constant (10 ⁻¹²) C/N	d ₁₁ =6.3
	d ₁₄ =-5.4
Phase speed m/s	2750 ~ 2850
Electromechanical coupling coefficient K (%)	0.28 ~ 0.46
Solubility	None
Coefficient of thermal expansion	a ₁₁ =5.15×10 ⁻⁶ K ⁻¹
	a ₃₃ =3.65×10 ⁻⁶ K ⁻¹

SPECTRA

